HD31557
SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Rack mount system
Class AB linear GaN design
Narrow bandwidth applications
Suitable for all single channel modulation standards
Built-in protection circuits
High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	1989 - 2001 MHz	
Power Output	50 Watt Min	CW
Power Gain	17 dB Min	30dBm Input required
Power Gain Flatness	1.0 dB p-p Max	
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	36dBm/Tone, Δ = 1MHz
Harmonics	-20 dBc Typ	At rated Pout
Non-Harmonics Spurious	-60 dBc Max	
Operating Voltage	100 - 240 VAC	
Power Consumption	300 Watt Typ	At rated Pout
Max Input Power	+33 dBm	Without damage
Load VSWR Protection	∞ : 1	

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50°C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensation

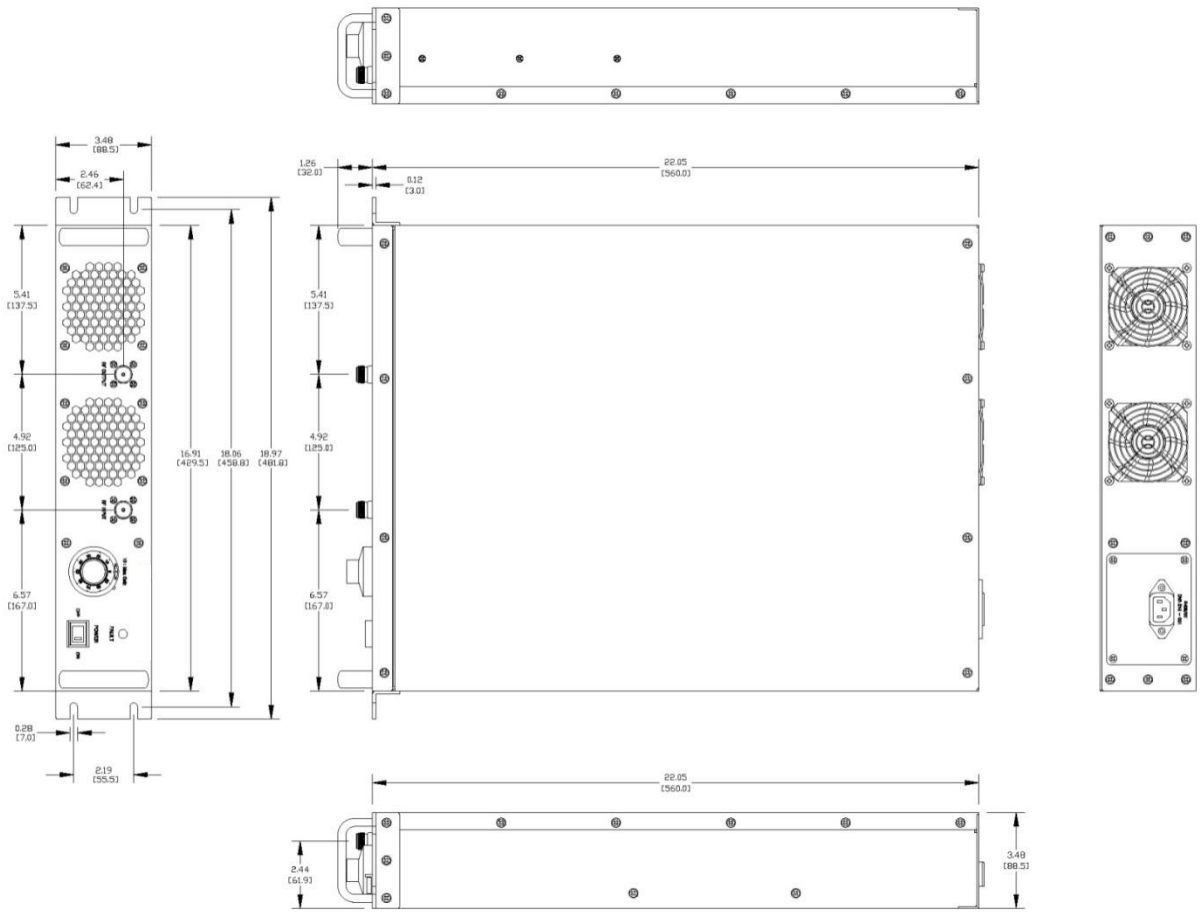
MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 88 x 560 mm	2U without handles & connectors
Weight	10 kg.	
RF Connectors In/Out	Type-N Female	Front Panel Standard
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	
Cooling	Built in Fan Cooling	
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485 Optional GPIB Interface	Remote Bluetooth application

332C Dante Ct. Holbrook, NY 11741 Phone: 631-588-3877 Fax: 631-648-0518
www.rfcomp.comwww.rfamplifiers.comsales@hdcom.com

HD31557
SOLID STATE HIGH POWER AMPLIFIER

OUTLINE DRAWING



332C Dante Ct. Holbrook, NY 11741 Phone: 631-588-3877 Fax: 631-648-0518
www.rfcomp.comwww.rfamplifiers.comsales@hdcom.com